

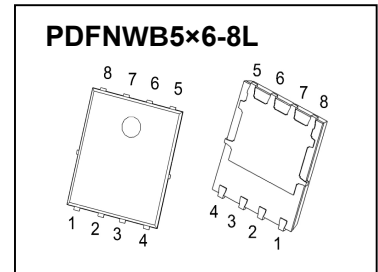


JIANGSU CHANGJING ELECTRONICS TECHNOLOGY CO., LTD.

PDFNWB5×6-8L Plastic-Encapsulate MOSFETS

CJAC150N03 N-Channel Power MOSFET

$V_{(BR)DSS}$	$R_{DS(on)TYP}$	I_D
30V	1.6mΩ@10V	150A
	2.1mΩ@4.5V	



DESCRIPTION

The CJAC150N03 uses advanced trench technology and design to provide excellent $R_{DS(ON)}$ with low gate charge. It can be used in a wide variety of applications

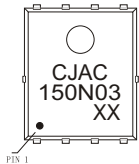
FEATURES

- Battery switch
- Load switch
- High density cell design for ultra low $R_{DS(ON)}$
- Fully characterized avalanche voltage and current
- Good stability and uniformity with high E_{AS}
- Excellent package for good heat dissipation
- Special process technology for high ESD capability

APPLICATIONS

- SMPS and general purpose applications
- Hard switched and high frequency circuits
- Uninterruptible Power Supply

MARKING

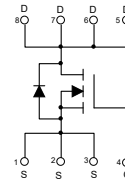


CJAC150N03 = Part No.

Solid dot = Pin1 indicator

XX= Code

EQUIVALENT CIRCUIT



MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V_{DS}	30	V
Gate-Source Voltage	V_{GS}	± 20	V
Continuous Drain Current	$I_D^{(1)}$	150	A
Pulsed Drain Current	$I_{DM}^{(2)}$	600	A
Single Pulsed Avalanche Energy	$E_{AS}^{(3)}$	280	mJ
Power Dissipation	$P_D^{(1)}$	130	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}^{(6)}$	62.5	$^{\circ}\text{C/W}$
Thermal Resistance from Junction to Case	$R_{\theta JC}^{(1)}$	0.96	$^{\circ}\text{C/W}$
Operating Junction and Storage Temperature Range	T_J, T_{stg}	-50~+150	$^{\circ}\text{C}$

MOSFET ELECTRICAL CHARACTERISTICS

T_a=25 °C unless otherwise specified

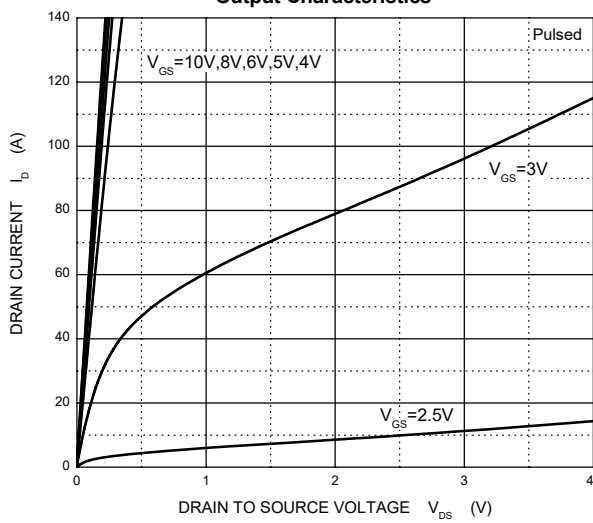
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	V _{(BR) DSS}	V _{GS} = 0V, I _D =250μA	30			V
Zero gate voltage drain current	I _{DSS}	V _{DS} =24V, V _{GS} =0V			1	μA
Gate-body leakage current	I _{GSS}	V _{DS} =0V, V _{GS} =±20V			±100	nA
On characteristics ④						
Gate-threshold voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =250μA	1.2	1.6	2.5	V
Static drain-source on-sate resistance	R _{DS(on)}	V _{GS} =10V, I _D =30A		1.6	2.0	mΩ
		V _{GS} =4.5V, I _D =15A		2.1	2.7	mΩ
Forward transconductance	g _{FS}	V _{DS} =10V, I _D =2A		17		S
Dynamic characteristics ④ ⑤						
Input capacitance	C _{iss}	V _{DS} =15V,V _{GS} =0V, f =1MHz		5400		pF
Output capacitance	C _{oss}			780		
Reverse transfer capacitance	C _{rss}			600		
Switching characteristics ④ ⑤						
Total gate charge	Q _g	V _{GS} =4.5V, V _{DS} =15V, I _D =24A		60		nC
Gate-source charge	Q _{gs}			11.1		
Gate-drain charge	Q _{gd}			9.5		
Turn-on delay time	t _{d(on)}	V _{DS} =15V,R _L =0.75Ω, V _{GS} =10V,R _G =1Ω		20		ns
Turn-on rise time	t _r			32		
Turn-off delay time	t _{d(off)}			75		
Turn-off fall time	t _f			28		
Drain-Source Diode Characteristics						
Drain-source diode forward voltage	V _{SD} ④	V _{GS} =0V, I _S =10A			1.0	V
Continuous drain-source diode forward current	I _S ①				150	A
Pulsed drain-source diode forward current	I _{SM} ②				600	A

Notes:

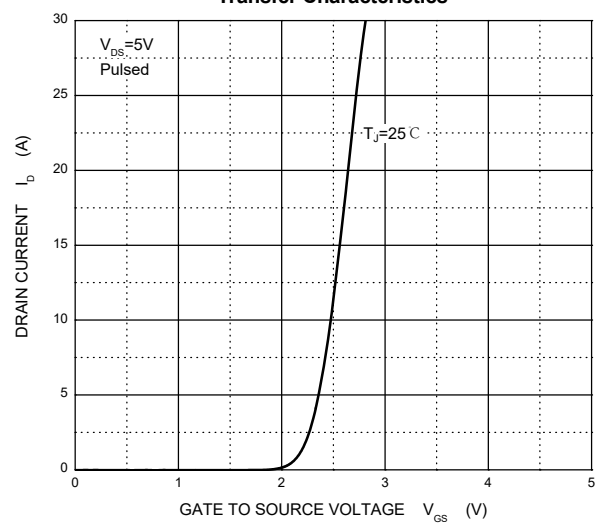
- 1.T_C=25 °C Limited only by maximum temperature allowed.
- 2.P_W≤10μs, Duty cycle≤1%.
- 3.EAS condition: V_{DD}=30V, V_{GS}=10V, L=0.1mH, R_G=25Ω Starting T_J = 25° °C.
- 4.Pulse Test : Pulse Width≤300μs, duty cycle ≤2%.
- 5.Guaranteed by design, not subject to production.
- 6.The value of R_{θJA} is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T_a=25 °C.

Typical Characteristics

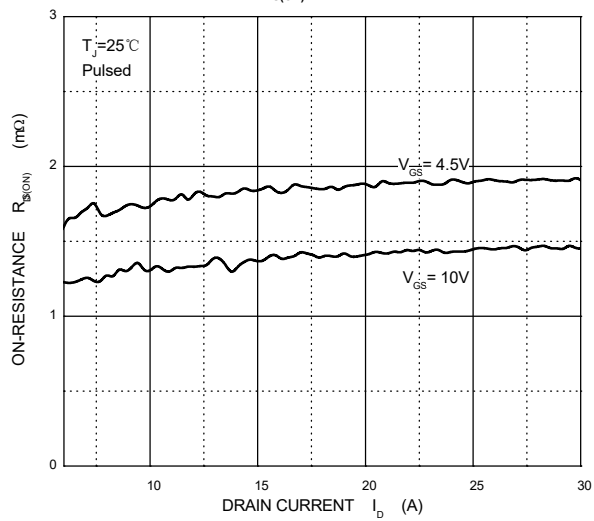
Output Characteristics



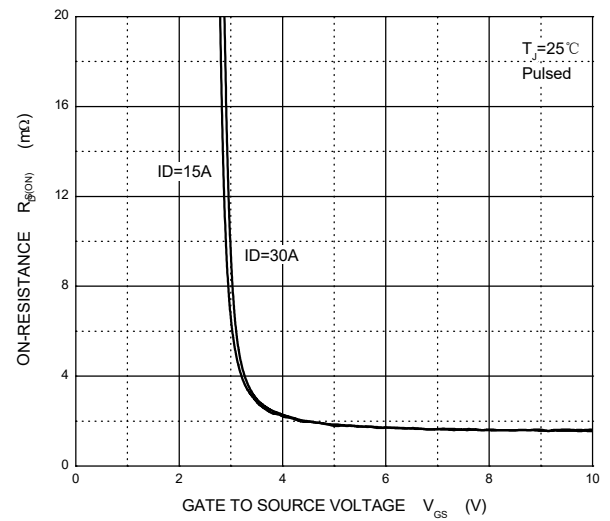
Transfer Characteristics



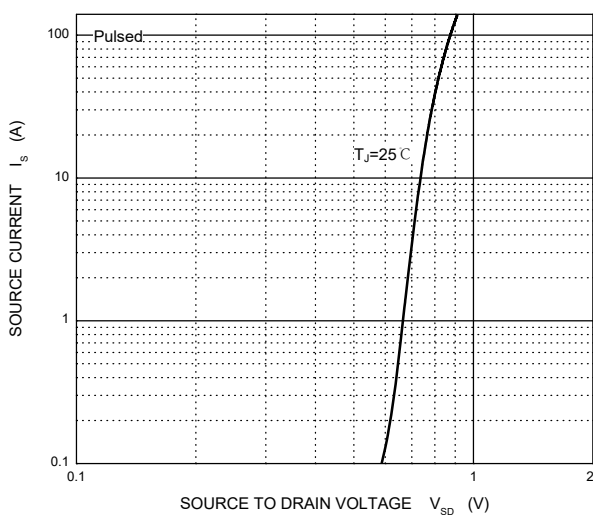
$R_{DS(ON)}$ — I_D



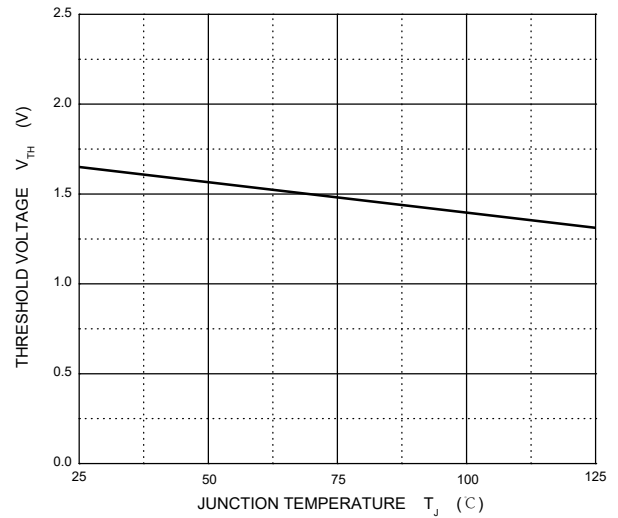
$R_{DS(ON)}$ — V_{GS}



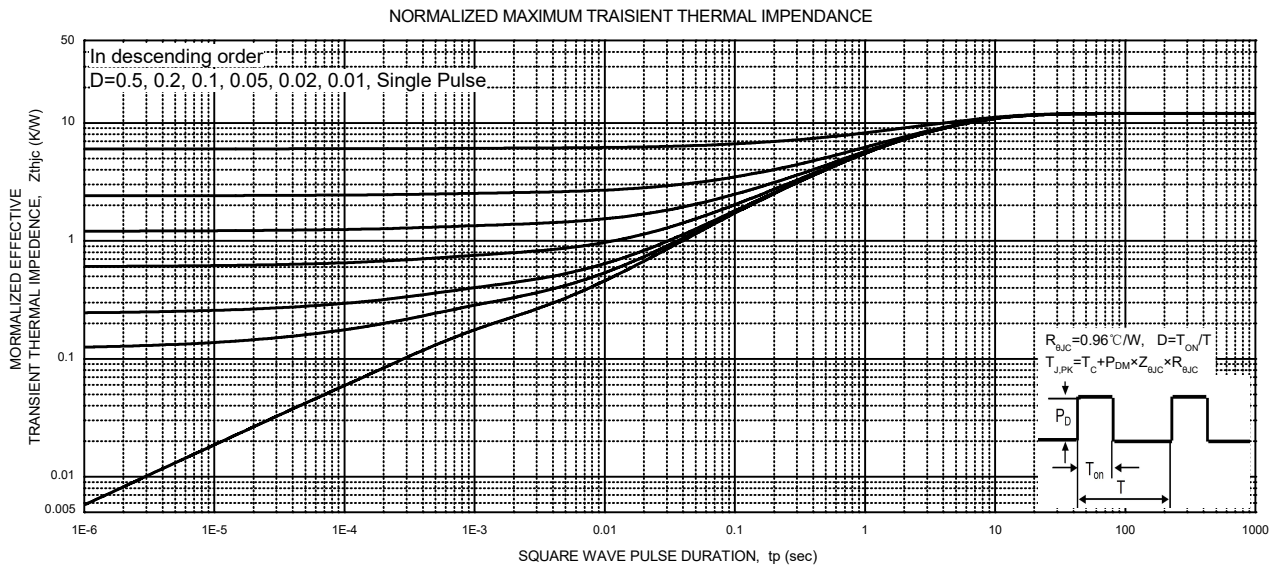
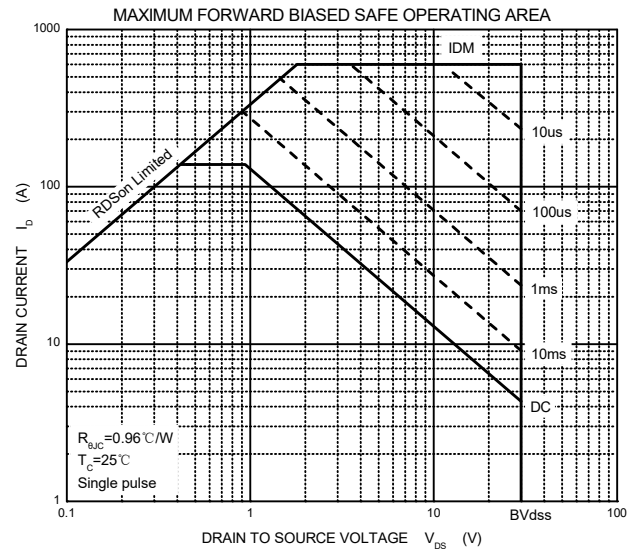
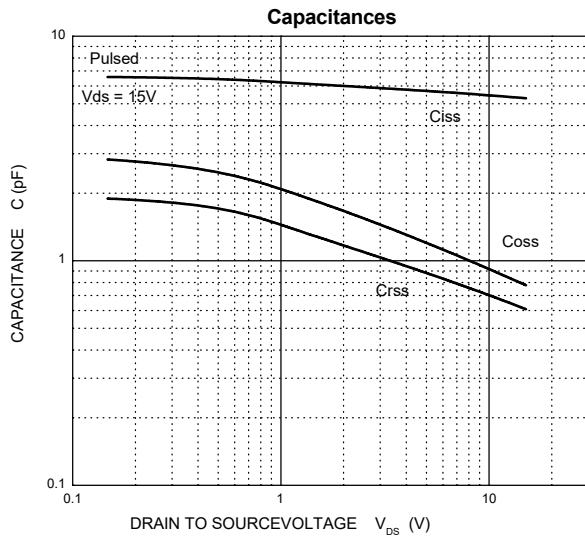
I_S — V_{SD}



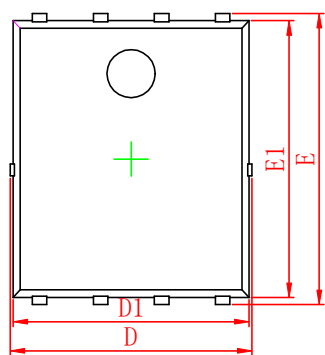
Threshold Voltage



Typical Characteristics



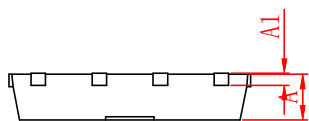
PDFNWB5×6-8L PACKAGE OUTLINE DIMENSIONS



Top View
[顶视图]



Bottom View
[背视图]

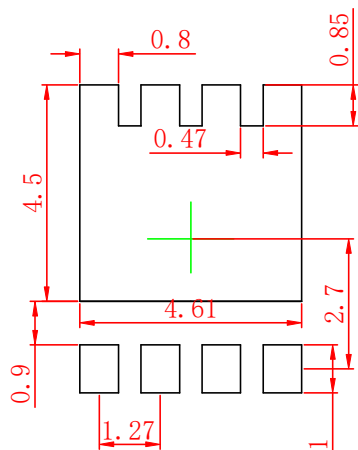


Side View
[侧视图]

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.90	1.10	0.035	0.043
A1	0.25 REF.		0.010 REF.	
D	4.90	5.10	0.193	0.201
D1	4.80	5.00	0.189	0.197
D2	3.90	4.10	0.154	0.161
E	5.90	6.10	0.232	0.240
E1	5.65	5.85	0.222	0.230
E2	3.35	3.65	0.132	0.144
k	1.20	1.50	0.047	0.059
b	0.20	0.45	0.008	0.018
e	1.27 BSC		0.050 BSC	
L	0.55	0.75	0.022	0.030
H	0.45	0.75	0.018	0.030

- Notes:
- 1 Dimensions exclusive of mold gate burrs.
 - 2 Dimensions exclusive of mold flash and cutting burrs.

PDFNWB5×6-8L Suggested Pad Layout



- Notes:
- 1 Controlling dimension: in millimeters.
 - 2 General tolerance:±0.05mm.
 - 3 The pad layout is for reference purpose only.

NOTICE

JSCJ reservesthe right to make modifications,enhancements,improvements,corrections or other changes without further notice to any product herein.JSCJ does not assume any liability arising out of the application or use of any product described herein.

PDFNWB5×6 Tape and Reel

PDFNWB5×6-8L Embossed Carrier Tape



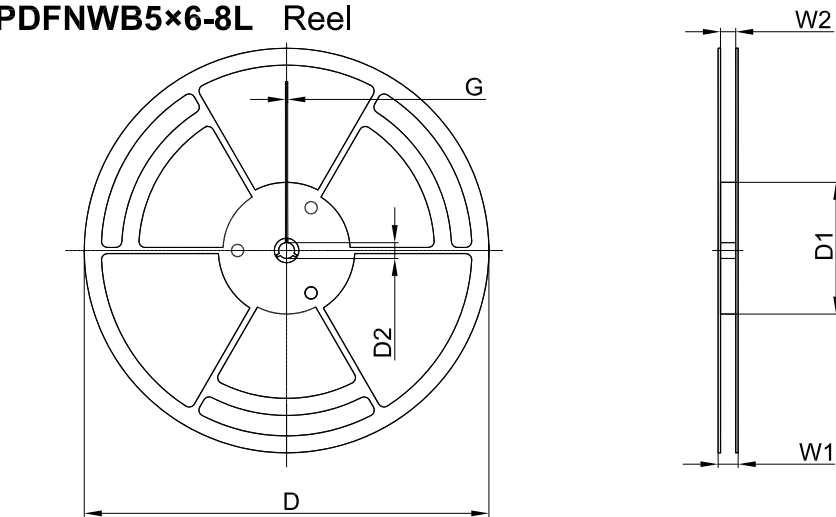
Packaging Description:
PDFNWB5×6-8L parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 5,000 units per 13" or 33.0 cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

Dimensions are in millimeter										
Pkg type	A	B	C	d	E	F	P0	P	P1	W
PDFNWB5×6-8L	6.30	5.30	1.10	Ø1.50	1.75	5.50	4.00	8.00	2.00	12.00

PDFNWB5×6-8L Tape Leader and Trailer



PDFNWB5×6-8L Reel



Dimensions are in millimeter						
Reel Option	D	D1	D2	G	W1	W2
13"Dia	Ø330.00	100.00	13.00	1.90	17.60	12.40

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)
5,000 pcs	13 inch	5,000 pcs	340×336×29	50,000 pcs	353×346×365